

Data Sheet January 2000 File Number 4050.1

4A, 1200V Ultrafast Dual Diode

The RURP4120CC is an ultrafast dual diode with soft recovery characteristics (t_{rr} < 70ns). It has low forward voltage drop and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49036.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURP4120CC	TO-220AB	RUR4120C

NOTE: When ordering, use the entire part number.

Symbol



Features

Ultrafast with Soft Recovery	.<70ns
Operating Temperature	.175 ⁰ C
Reverse Voltage	.1200V

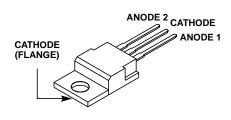
- Avalanche Energy Rated
- · Planar Construction

Applications

- · Switching Power Supplies
- Power Switching Circuits
- General Purpose

Packaging

JEDEC TO-220AB



Absolute Maximum Ratings (Per Leg) T_C = 25°C, Unless Otherwise Specified **UNITS** RURP4120CC Peak Repetitive Reverse Voltage...... VRRM 1200 1200 1200 V 4 $T_{\rm C} = 152^{\rm o}{\rm C}$ Repetitive Peak Surge Current I_{FRM} 8 Square Wave, 20kHz 40 Α Halfwave, 1 Phase, 60Hz 50 W 10 mJ οС -65 to 175

Electrical Specifications (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 4A	-	-	2.1	V
	$I_F = 4A, T_C = 150^{\circ}C$	-	-	1.9	V
I _R	V _R = 1200V	-	-	100	μΑ
	V _R = 1200V, T _C = 150°C	-	-	500	μΑ
t _{rr}	$I_F = 1A$, $dI_F/dt = 200A/\mu s$	-	-	70	ns
	$I_F = 4A$, $dI_F/dt = 200A/\mu s$	-	-	90	ns
t _a	$I_F = 4A$, $dI_F/dt = 200A/\mu s$	-	40	-	ns
t _b	$I_F = 4A$, $dI_F/dt = 200A/\mu s$	-	28	-	ns
Q _{RR}	$I_F = 4A$, $dI_F/dt = 200A/\mu s$	-	335	-	nC
CJ	V _R = 10V, I _F = 0A	-	15	-	pF
R _{θJC}		-	-	3	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of t_a + t_b .

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

 Q_{RR} = Reverse recovery charge.

 C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

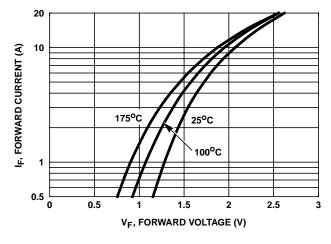


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

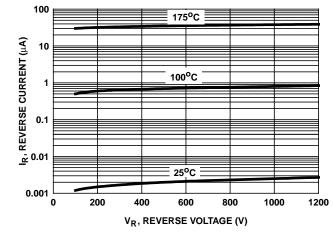


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

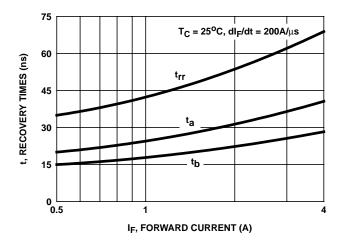


FIGURE 3. t_{rr} , t_a and t_b curves vs forward current

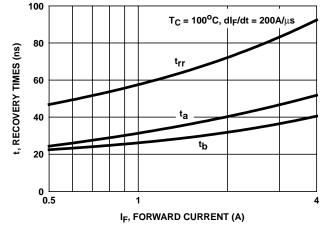


FIGURE 4. t_{rr} , t_a and t_b curves vs forward current

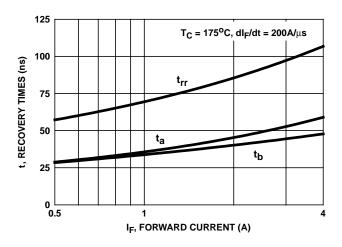


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

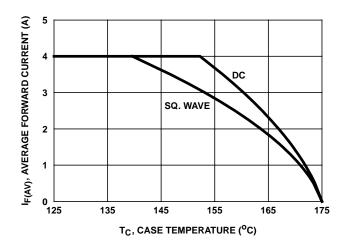


FIGURE 6. CURRENT DERATING CURVE

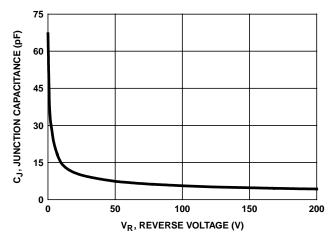


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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Test Circuits and Waveforms

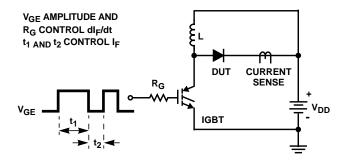


FIGURE 8. t_{rr} TEST CIRCUIT

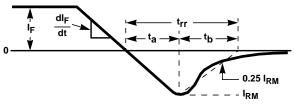


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

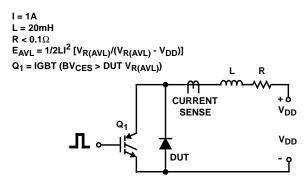


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

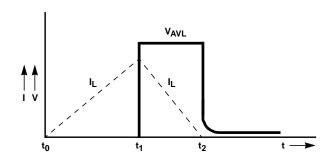


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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